SN74LVCZ32245A 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS SCES423 – JANUARY 2003

- Member of the Texas Instruments Widebus+[™] Family
- Operates From 2.7 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 3.7 ns at 3.3 V
- I_{off} and Power-Up 3-State Support Hot Insertion
- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22

 2000-V Human-Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)

| | GKE PACKAGE (TOP VIEW) | | | | | | | |
|---|---------------------------|---|------------|------------|------------|------------|------------|---|
| | _ | 1 | 2 | 3 | 4 | 5 | 6 | _ |
| A | | С | \bigcirc | С | \bigcirc | \bigcirc | С | |
| в | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| С | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| D | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| Е | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| F | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| G | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| н | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| J | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| к | (| С | С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| L | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| м | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| Ν | (| С | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | |
| Р | (| С | С | \bigcirc | \bigcirc | \bigcirc | С | |
| R | (| С | С | С | С | С | С | |
| т | (| С | С | С | С | С | С | |
| | | | | | | | | Ϊ |

terminal assignments

| | 1 | 2 | 3 | 4 | 5 | 6 |
|---|-----|-----|-----------------|-------------------|-----|-----|
| Α | 1B2 | 1B1 | 1DIR | 1 <mark>0E</mark> | 1A1 | 1A2 |
| в | 1B4 | 1B3 | GND | GND | 1A3 | 1A4 |
| С | 1B6 | 1B5 | VCC | VCC | 1A5 | 1A6 |
| D | 1B8 | 1B7 | GND | GND | 1A7 | 1A8 |
| Е | 2B2 | 2B1 | GND | GND | 2A1 | 2A2 |
| F | 2B4 | 2B3 | V _{CC} | V _{CC} | 2A3 | 2A4 |
| G | 2B6 | 2B5 | GND | GND | 2A5 | 2A6 |
| н | 2B7 | 2B8 | 2DIR | 2 <mark>0E</mark> | 2A8 | 2A7 |
| J | 3B2 | 3B1 | 3DIR | 3OE | 3A1 | 3A2 |
| κ | 3B4 | 3B3 | GND | GND | 3A3 | 3A4 |
| L | 3B6 | 3B5 | VCC | VCC | 3A5 | 3A6 |
| М | 3B8 | 3B7 | GND | GND | 3A7 | 3A8 |
| Ν | 4B2 | 4B1 | GND | GND | 4A1 | 4A2 |
| Ρ | 4B4 | 4B3 | V _{CC} | V _{CC} | 4A3 | 4A4 |
| R | 4B6 | 4B5 | GND | GND | 4A5 | 4A6 |
| т | 4B7 | 4B8 | 4DIR | 4OE | 4A8 | 4A7 |

description/ordering information

This 32-bit (quad-octal) noninverting bus transceiver is designed for 2.7-V to 3.6-V V_{CC} operation.

The SN74LVCZ32245A is designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements.

ORDERING INFORMATION

| TA | PACKAGET | | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|---------------|-------------|---------------|--------------------------|---------------------|
| -40°C to 85°C | LFBGA – GKE | Tape and reel | SN74LVCZ32245AGKER | ZC245A |

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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description/ordering information (continued)

This device can be used as four 8-bit transceivers, two 16-bit transceivers, or one 32-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

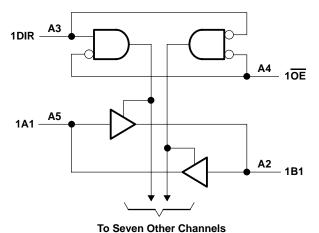
This device is fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

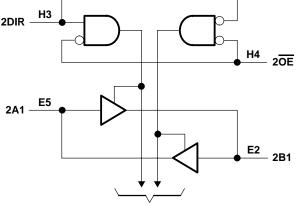
| (each o-bit Section) | | | | | | |
|----------------------|-----|-----------------|--|--|--|--|
| INP | UTS | | | | | |
| OE | DIR | OPERATION | | | | |
| L | L | B data to A bus | | | | |
| L | Н | A data to B bus | | | | |
| Н | Х | Isolation | | | | |

FUNCTION TABLE (each 8-bit section)

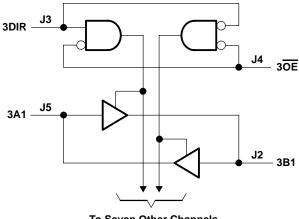


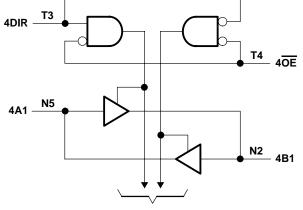
logic diagram (positive logic)





To Seven Other Channels





To Seven Other Channels

To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1) | |
|---|-----------------------------------|
| Voltage range applied to any output in the high-impedance or power-off state, V _O (see Note 1) | –0.5 V to 6.5 V |
| Voltage range applied to any output in the high or low state, V _O | |
| (see Notes 1 and 2) | –0.5 V to V _{CC} + 0.5 V |
| Input clamp current, I _{IK} (V _I < 0) | –50 mA |
| Output clamp current, I_{OK} ($V_O < 0$) | |
| Continuous output current, I _O | ±50 mA |
| Continuous current through each V _{CC} or GND | |
| Package thermal impedance, θ_{JA} (see Note 2) | |
| Storage temperature range, T _{stg} | |

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed. 2. The value of V_{CC} is provided in the recommended operating conditions table.

- 3. The package thermal impedance is calculated in accordance with JESD 51-7.



SN74LVCZ32245A **32-BIT BUS TRANSCEIVER** WITH 3-STATE OUTPUTS

SCES423 – JANUARY 2003

recommended operating conditions (see Note 4)

| | | | MIN | MAX | UNIT |
|----------------------------|--|--|-----|-----|------|
| VCC | Supply voltage | | 2.7 | 3.6 | V |
| VIH | High-level input voltage | V_{CC} = 2.7 V to 3.6 V | 2 | | V |
| VIL | Low-level input voltage | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | | 0.8 | V |
| VI | Input voltage | | 0 | 5.5 | V |
| | | High or low state | 0 | VCC | |
| VO | Output voltage 3-state | | 0 | 5.5 | V |
| | 1 Path Incode a devide a second | $V_{CC} = 2.7 V$ | | -12 | |
| ЮН | High-level output current | $V_{CC} = 3 V$ | | -24 | mA |
| | Low-level output current $\frac{V_{CC} = 2.7 \text{ V}}{V_{CC} = 3 \text{ V}}$ | | | 12 | |
| IOL | | | | 24 | mA |
| $\Delta t/\Delta v$ | Input transition rise or fall rate | | | 6 | ns/V |
| $\Delta t / \Delta V_{CC}$ | Power-up ramp rate | | 150 | | μs/V |
| т _А | Operating free-air temperature | | -40 | 85 | °C |

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

| electrical characteristics | over | recommended | operating | free-air | temperature | range | (unless |
|----------------------------|------|-------------|-----------|----------|-------------|-------|---------|
| otherwise noted) | | | | | - | - | - |

| P | ARAMETER | TEST CONDITI | ONS | Vcc | MIN | TYP† | MAX | UNIT |
|-------------------|----------------|--|--------------------------------|----------------|----------------------|------|-----|------|
| | | I _{OH} = -100 μA | | 2.7 V to 3.6 V | V _{CC} -0.2 | | | |
| ., | | | | 2.7 V | 2.2 | | | ., |
| VOH | | $I_{OH} = -12 \text{ mA}$ | | 3 V | 2.4 | | | V |
| | | I _{OH} = -24 mA | | 3 V | 2.2 | | | |
| | | I _{OL} = 100 μA | | 2.7 V to 3.6 V | | | 0.2 | |
| VOL | | I _{OL} = 12 mA | | 2.7 V | | | 0.4 | V |
| | | I _{OL} = 24 mA | 3 V | | | 0.55 | | |
| Ц | Control inputs | V _I = 0 to 5.5 V | | 3.6 V | | | ±5 | μA |
| l _{off} | | $V_{I} \text{ or } V_{O} = 5.5 \text{ V}$ | | 0 | | | ±5 | μΑ |
| I _{OZ} ‡ | | $V_{O} = 0$ to 5.5 V | | 3.6 V | | | ±5 | μΑ |
| IOZPU | J | $V_{O} = 0.5 V$ to 2.5 V, | OE = don't care | 0 to 1.5 V | | | ±5 | μΑ |
| IOZPE |) | $V_{O} = 0.5 V$ to 2.5 V, | OE = don't care | 1.5 V to 0 | | | ±5 | μΑ |
| | | VI = V _{CC} or GND | | | | | 120 | |
| ICC | | $3.6 \text{ V} \le \text{V}_I \le 5.5 \text{ V}$ | IO = 0 | 3.6 V | | | 120 | μA |
| $\Delta I C C$ | | One input at V _{CC} – 0.6 V, Other in | puts at V _{CC} or GND | 2.7 V to 3.6 V | | | 500 | μΑ |
| Ci | Control inputs | $V_I = V_{CC}$ or GND | | 3.3 V | | 5 | | pF |
| Cio | A or B ports | $V_{O} = V_{CC}$ or GND | | 3.3 V | | 6.5 | | pF |

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. [‡] For I/O ports, the parameter I_{OZ} includes the input leakage current.

§ This applies in the disabled state only.



switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM | TO | V _{CC} = 2.7 V | | = V _{CC} ± 0.3 | 3.3 V 3 V | UNIT |
|------------------|---------|----------|-------------------------|-----|----------------------------|--------------|------|
| | (INPUT) | (OUTPUT) | MIN | MAX | MIN | MAX | |
| ^t pd | A or B | B or A | | 4.2 | 1.3 | 4 | ns |
| ten | OE | A or B | | 6.1 | 1.4 | 5.6 | ns |
| ^t dis | OE | A or B | | 7.1 | 2 | 6.6 | ns |

switching characteristics over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM | TO | V _{CC} = 2.7 V | ۲ <mark>0.5</mark> V _{CC} = | 3.3 V 3 V | UNIT |
|------------------|---------|----------|-------------------------|--------------------------------------|--------------|------|
| | (INPUT) | (OUTPUT) | MIN MAX | MIN | MAX | |
| ^t pd | A or B | B or A | 3.9 | 1 | 3.7 | ns |
| ten | OE | A or B | 5.9 | 1.1 | 5.4 | ns |
| ^t dis | OE | A or B | 6.7 | 1.6 | 6.2 | ns |

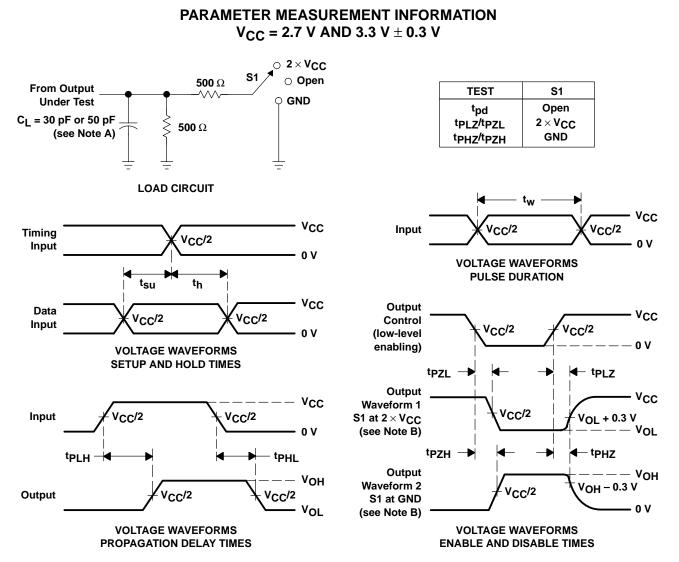
operating characteristics, $T_A = 25^{\circ}C$

| | PARAMETER | | TEST | V _{CC} = 3.3 V | |
|-----|---|------------------|------------|-------------------------|------|
| | PARAMETER | | | TYP | UNIT |
| Cpd | | Outputs enabled | f = 10 MHz | 42 | ٥F |
| ∽pd | Power dissipation capacitance per transceiver | Outputs disabled | | 4 | рг |



SN74LVCZ32245A 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

SCES423 - JANUARY 2003



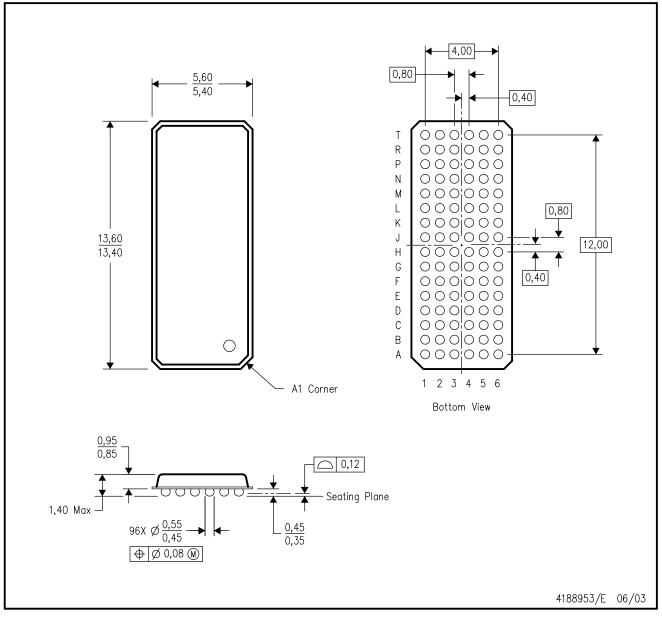
- NOTES: A. CI includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2 ns, t_f \leq 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



GKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. MicroStar BGA™ configuration
 - D. Falls within JEDEC MO-205 variation CC.
 - E. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.

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